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Virtual Simulator

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Abstract: *This paper is based on virtual experiment approaches to Gunn diode and their vi characteristics. Virtual labs which provide remote-access to simulation-based Labs in various disciplines of Science and Engineering. In microwave and radar engineering, virtual experiments are not available. In this paper, we consider vi characteristics of Gunn diode. In this experiment without actual use of power supply we performing experiment virtually. Evaluation using web technology we introduced this experiment. Gunn devices were simulated using the Sentaurus Device software. The fabricated planar Gunn diodes are 1.3 μm long and 120 micron wide and the measured and simulated results are in excellent agreement. This experiment involving the changes in current and voltage. We further show applications and experiment actual and virtual setup.*

Keywords: Virtual Experiment

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